

TRIAC(Through Hole / Isolated)

TMG25D60F

(Sensitive Gate)

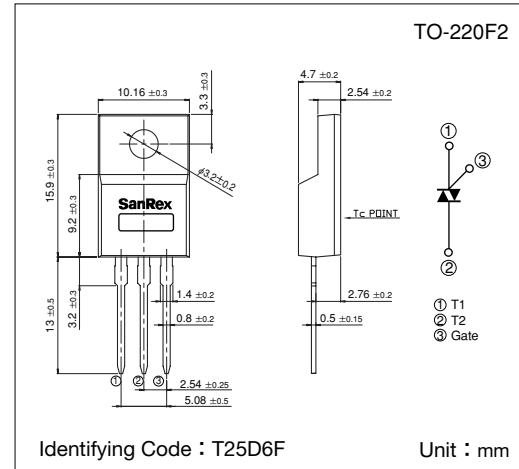
SanRex Triac TMG25D60F is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

Features

- $I_{T(RMS)}=25A$
- High Surge Current
- Low Voltage Drop
- Lead-Free Package



■ Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Item | Reference | Ratings | | Unit |
|--------------|--------------------------------------|---|----------|--|------------------|
| V_{DRM} | Repetitive Peak Off-State Voltage | | 600 | | V |
| $I_{T(RMS)}$ | R.M.S. On-State Current | $T_c=68^\circ\text{C}$ | 25 | | A |
| I_{tSM} | Surge On-State Current | One cycle, 50Hz/60Hz, Peak value non-repetitive | 225/250 | | A |
| I^2t | I^2t (for fusing) | | 260 | | A ² S |
| P_{GM} | Peak Gate Power Dissipation | | 5 | | W |
| $P_{G(AV)}$ | Average Gate Power Dissipation | | 0.5 | | W |
| I_{GM} | Peak Gate Current | | 2 | | A |
| V_{GM} | Peak Gate Voltage | | 10 | | V |
| V_{ISO} | Isolation Breakdown Voltage (R.M.S.) | A.C. 1minute | 1500 | | V |
| T_j | Operating Junction Temperature | | -40~+125 | | °C |
| T_{stg} | Storage Temperature | | -40~+150 | | °C |
| | Mass | | 2.2 | | g |

■ Electrical Characteristics

| Symbol | Item | Reference | Ratings | | | Unit | |
|------------------|---|---|---------|------|------|---------------------------|--|
| | | | Min. | Typ. | Max. | | |
| I_{DRM} | Repetitive Peak Off-State Current | $V_D=V_{DRM}$, Single phase, half wave, $T_j=125^\circ\text{C}$ | | | 5 | mA | |
| V_{TM} | Peak On-State Voltage | $I_t=35\text{A}$, Inst. measurement | | | 1.4 | V | |
| I_{GT1}^+ 1 | Gate Trigger Current | $V_D=6\text{V}$, $R_L=10\Omega$ | | | 10 | mA | |
| I_{GT1}^- 2 | | | | | 10 | | |
| I_{GT3}^+ 3 | | | | | — | | |
| I_{GT3}^- 4 | | | | | 10 | | |
| V_{GT1}^+ 1 | Gate Trigger Voltage | | | | 1.5 | V | |
| V_{GT1}^- 2 | | | | | 1.5 | | |
| V_{GT3}^+ 3 | | | | | — | | |
| V_{GT3}^- 4 | | | | | 1.5 | | |
| V_{GD} | Non-Trigger Gate Voltage | $T_j=125^\circ\text{C}$, $V_D=\frac{1}{2}V_{DRM}$ | 0.2 | | | V | |
| $[dv/dt]_c$ | Critical Rate of Rise of Off-State Voltage at Commutation | $T_j=125^\circ\text{C}$, $[di/dt]_c=-12.5\text{A/ms}$, $V_D=\frac{2}{3}V_{DRM}$ | 10 | | | $\text{V}/\mu\text{s}$ | |
| I_H | Holding Current | | | 35 | | mA | |
| R_{th} | Thermal Resistance | Junction to case | | | 1.9 | $^\circ\text{C}/\text{W}$ | |

Trigger mode of the triac

